

Electronic structure of the $\text{Bi}_4\text{V}_2\text{O}_{11}$ (001) surface by ARPES

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BiVO_4 is one of the most widely investigated photoanode catalysts for water splitting to produce O_2 ¹. $\text{Bi}_4\text{V}_2\text{O}_{11}$ is composed of the same elements as BiVO_4 but exhibits different photocatalytic performance². To elucidate the factors that play an essential role in the photocatalytic process, the electronic-structure understanding of the $\text{Bi}_4\text{V}_2\text{O}_{11}$ surface is adequate. Until now, the theoretical study based on the density functional theory² has predicted a direct bandgap nature of $\text{Bi}_4\text{V}_2\text{O}_{11}$. However, since experimental verification of the $\text{Bi}_4\text{V}_2\text{O}_{11}$ surface is insufficient, the current study provides a basis for understanding the relationship between the surface electronic structure and photocatalysis.

A single-domain $\text{Bi}_4\text{V}_2\text{O}_{11}$ film was deposited on the Nb-doped STO (001) substrate by RF-sputtering. We characterized the $\text{Bi}_4\text{V}_2\text{O}_{11}$ (001) surface by low-energy electron diffraction (LEED) and angle-resolved photoemission spectroscopy (ARPES) at BL-3B of the Photon Factory. The results show that the clean crystal surface exhibits a $\frac{\sqrt{2}}{2} \times \frac{\sqrt{2}}{2}$ $R45^\circ$ pattern (Figure 1b), consistent with the (001) orientation of the surface (Figure 1a). The valance band maximum (VBM) is composed of a hybrid state between the Bi 6s lone pair states and O 2p states³. This antibonding state is remarkable in $\text{Bi}_4\text{V}_2\text{O}_{11}$, which causes the shift of VBM to a lower binding energy position compared with BiVO_4 . The ARPES results reveal that the Γ point is the local maximum of the VBM (figure 1c), which is consistent with the theoretical calculation². By fitting the dispersion, the effective mass of the hole was obtained as $7.13 \pm 0.60 m_e$. This huge effective mass could be considered as one reason for unsatisfactory photocatalytic performance.

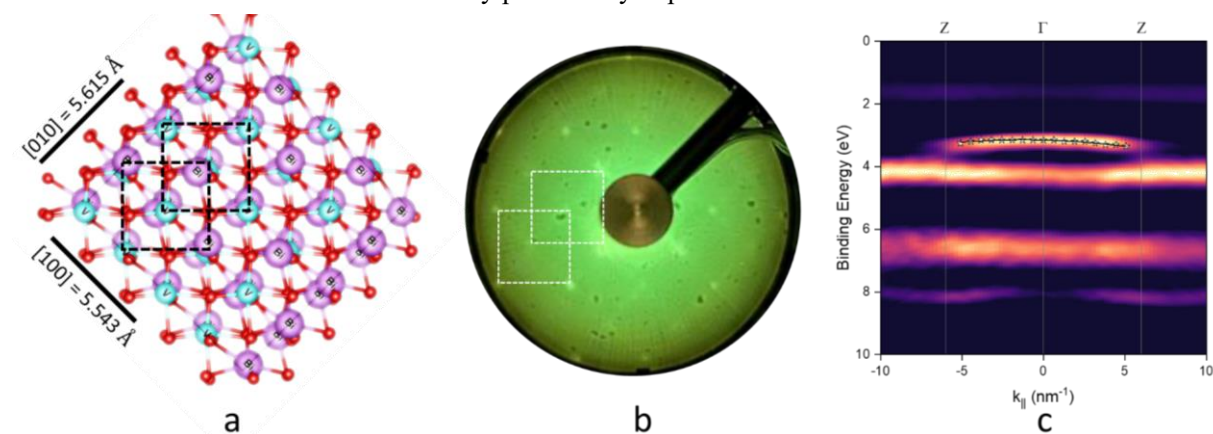


Figure 1. (a) Structure of $\text{Bi}_4\text{V}_2\text{O}_{11}$ (001) surface. (b) The LEED pattern (76 eV) displaying a $\frac{\sqrt{2}}{2} \times \frac{\sqrt{2}}{2}$ $R45^\circ$ pattern. (c) The representative ARPES image along the ΓZ direction measured with 59 eV photons.

References

1. J.H. Kim and J.S. Lee, Adv. Mater. **31**, 1806938 (2019).
2. Z. Jiang, Y. Liu, M. Li, T. Jing, B. Huang, X. Zhang, X. Qin, and Y. Dai, Sci. Rep. **6**, 22727 (2016).
3. D.J. Payne, M.D.M. Robinson, R.G. Egdell, A. Walsh, J. McNulty, K.E. Smith, and L.F.J. Piper, Appl. Phys. Lett. **98**, 212110 (2011).